

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (L²-π-MOSV)

2SJ508

Chopper Regulator, DC-DC Converter and Motor Drive Applications

- 4-V gate drive
- Low drain-source ON resistance : $R_{DS(ON)} = 1.34 \Omega$ (typ.)
- High forward transfer admittance : $|Y_{fs}| = 0.7 S$ (typ.)
- Low leakage current : $I_{DSS} = -100 \mu A$ (max) ($V_{DS} = -100 V$)
- Enhancement mode : $V_{th} = -0.8$ to $-2.0 V$ ($V_{DS} = -10 V, I_D = -1 mA$)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|--|----------------|-----------|------------|------|
| Drain-source voltage | | V_{DSS} | -100 | V |
| Drain-gate voltage ($R_{GS} = 20 k\Omega$) | | V_{DGR} | -100 | V |
| Gate-source voltage | | V_{GSS} | ± 20 | V |
| Drain current | DC (Note 1) | I_D | -1 | A |
| | Pulse (Note 1) | I_{DP} | -3 | A |
| Drain power dissipation | | P_D | 0.5 | W |
| Drain power dissipation (Note 2) | | P_D | 1.5 | W |
| Single pulse avalanche energy (Note 3) | | E_{AS} | 136.5 | mJ |
| Avalanche current | | I_{AR} | -1 | A |
| Repetitive avalanche energy (Note 4) | | E_{AR} | 0.05 | mJ |
| Channel temperature | | T_{ch} | 150 | °C |
| Storage temperature range | | T_{stg} | -55 to 150 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

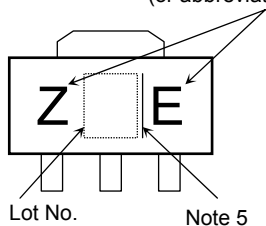
Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|----------------|-----|--------|
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 250 | °C / W |

- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)
- Note 3: $V_{DD} = -50 V, T_{ch} = 25^\circ C$ (initial), $L = 168 mH, R_G = 25 \Omega, I_{AR} = -1 A$
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

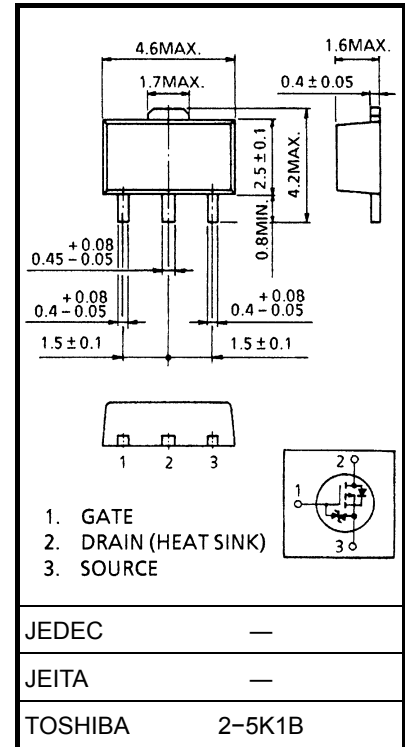
Marking



- Note 5: A line to the right of a Lot No. identifies the indication of product Labels.
 Without a line: $[[Pb]]/INCLUDES > MCV$
 With a line: $[[G]]/RoHS COMPATIBLE$ or $[[G]]/RoHS [[Pb]]$

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Unit: mm



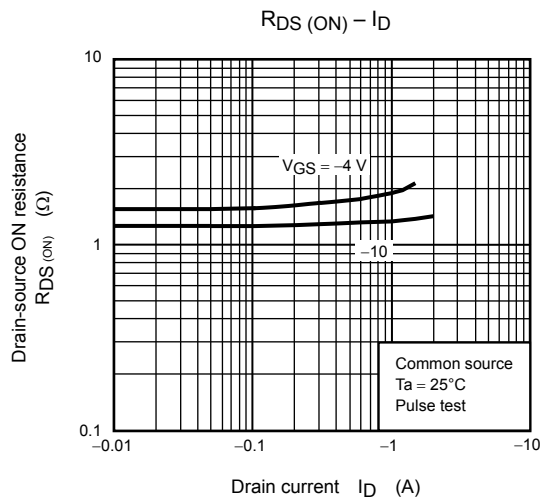
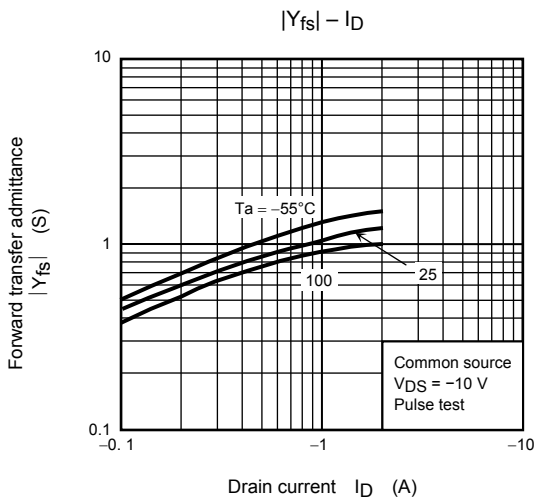
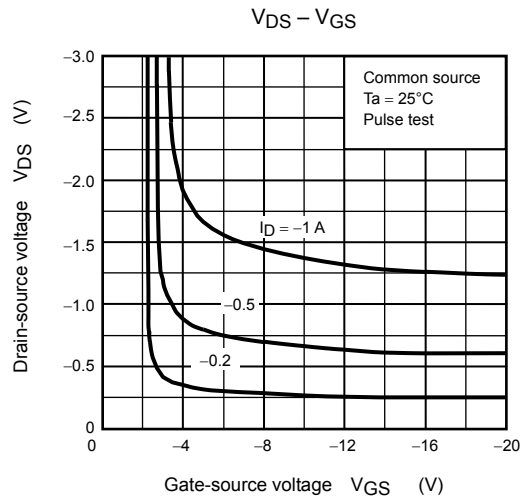
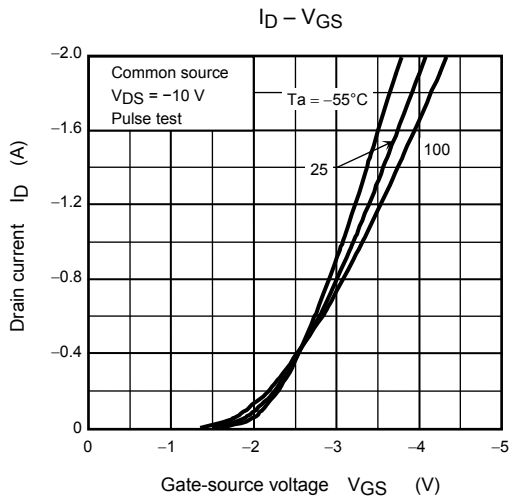
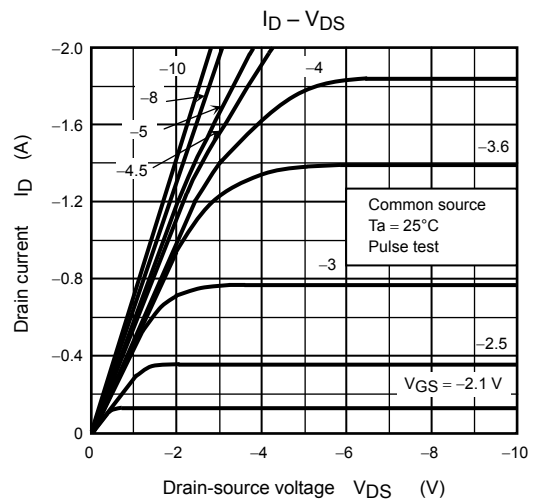
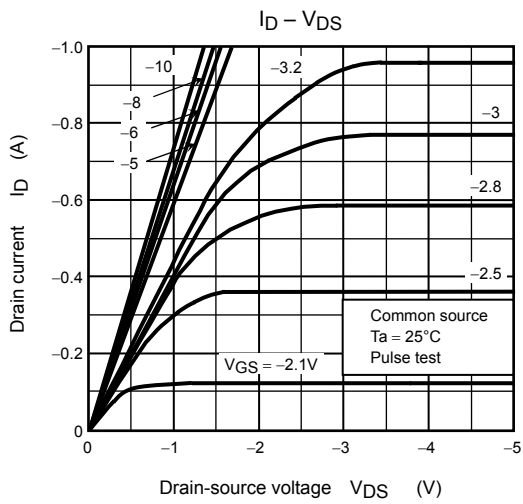
Weight: 0.05 g (typ.)

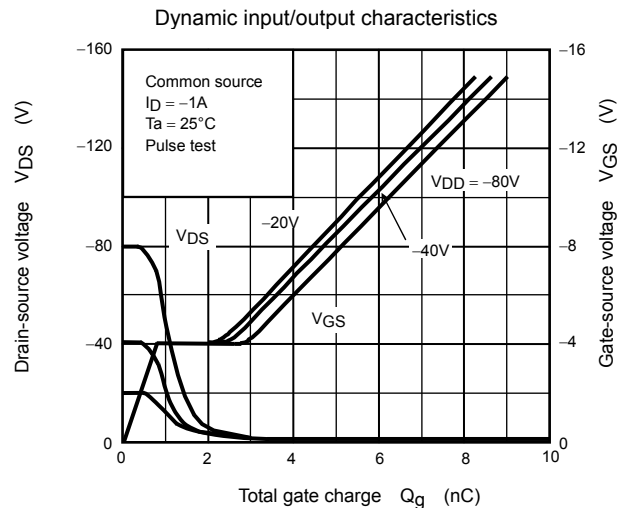
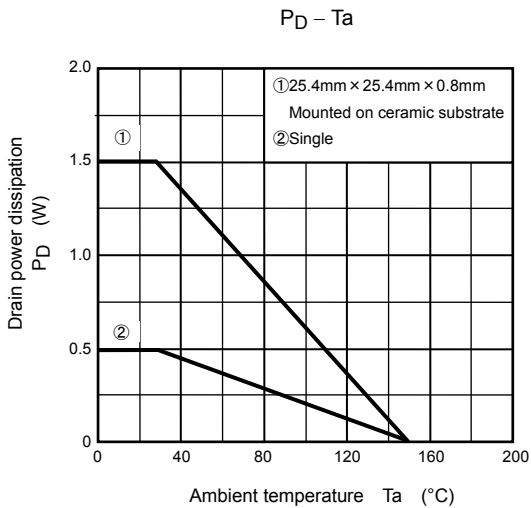
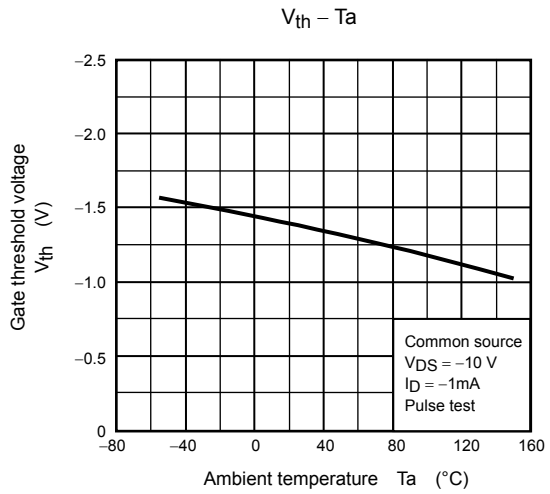
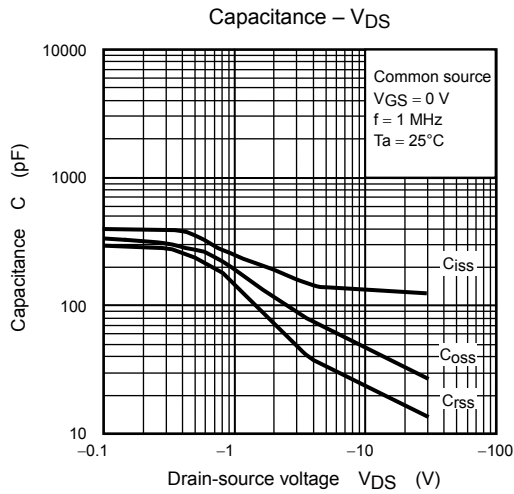
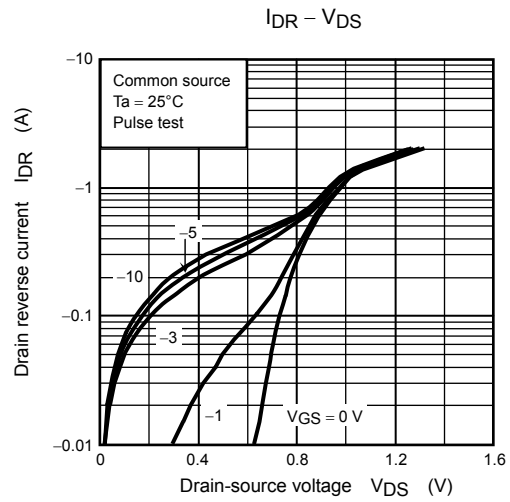
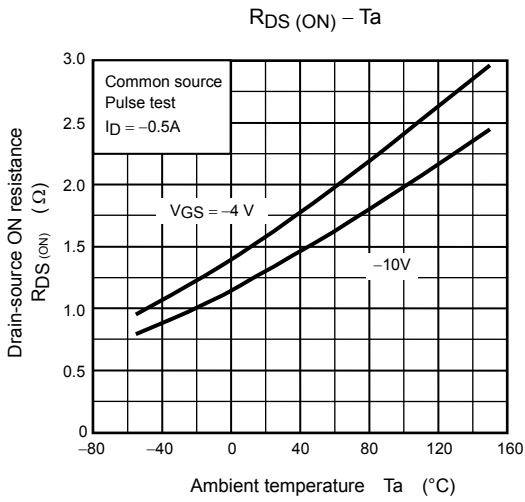
Electrical Characteristics (Ta = 25°C)

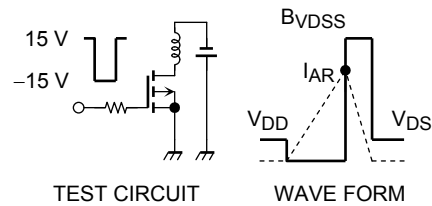
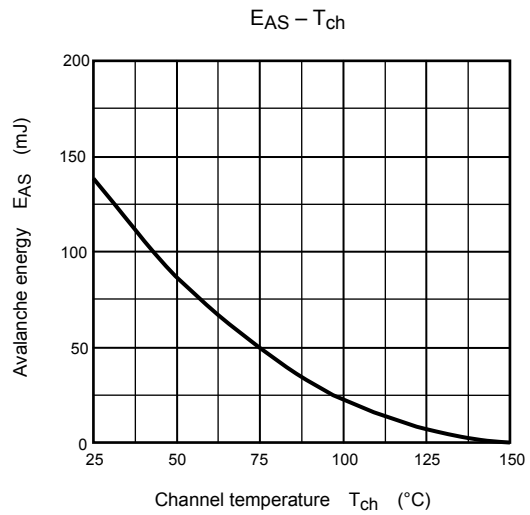
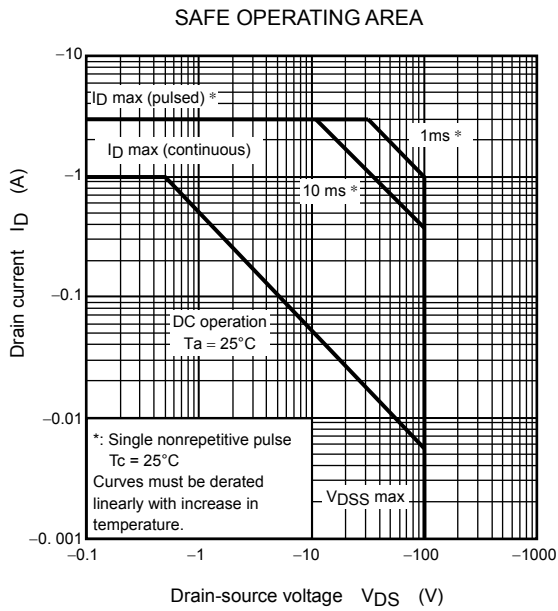
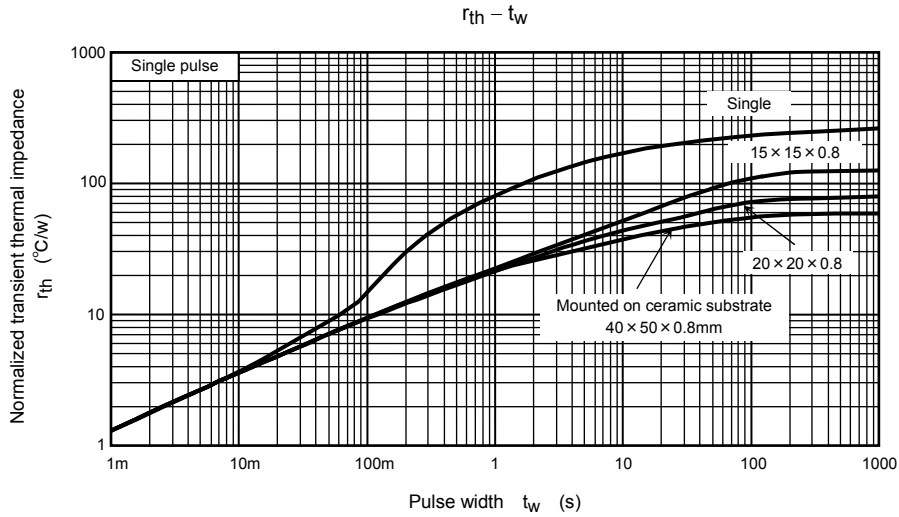
| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---------------|---------------|---|------|------|----------|---------------|
| Gate leakage current | | I_{GSS} | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$ | — | — | ± 10 | μA |
| Drain cut-off current | | I_{DSS} | $V_{DS} = -100 \text{ V}, V_{GS} = 0 \text{ V}$ | — | — | -100 | μA |
| Drain-source breakdown voltage | | $V_{(BR)DSS}$ | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -100 | — | — | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$ | -0.8 | — | -2.0 | V |
| Drain-source ON resistance | | $R_{DS(ON)}$ | $V_{GS} = -4 \text{ V}, I_D = -0.5 \text{ A}$ | — | 1.68 | 2.5 | Ω |
| | | | $V_{GS} = -10 \text{ V}, I_D = -0.5 \text{ A}$ | — | 1.34 | 1.9 | |
| Forward transfer admittance | | $ Y_{fs} $ | $V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ A}$ | 0.3 | 0.7 | — | S |
| Input capacitance | | C_{iss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | — | 135 | — | pF |
| Reverse transfer capacitance | | C_{rss} | | — | 22 | — | |
| Output capacitance | | C_{oss} | | — | 48 | — | |
| Switching time | Rise time | t_r | <p>$I_D = -0.5 \text{ A}$ $V_{DD} \approx -50 \text{ V}$ $R_L = 100 \Omega$ $V_{GS} = 0 \text{ V}$ $V_{GS} = -10 \text{ V}$ 50Ω V_{OUT} $Duty \leq 1\%, t_w = 10 \mu\text{s}$</p> | — | 20 | — | ns |
| | Turn-on time | t_{on} | | — | 32 | — | |
| | Fall time | t_f | | — | 25 | — | |
| | Turn-off time | t_{off} | | — | 130 | — | |
| Total gate charge (Gate-source plus gate-drain) | | Q_g | $V_{DD} \approx -80 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$ | — | 6.3 | — | nC |
| Gate-source charge | | Q_{gs} | | — | 4.1 | — | |
| Gate-drain ("miller") charge | | Q_{gd} | | — | 2.2 | — | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Continuous drain reverse current (Note 1) | I_{DR} | — | — | — | -1 | A |
| Pulse drain reverse current (Note 1) | I_{DRP} | — | — | — | -3 | A |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = -1 \text{ A}, V_{GS} = 0 \text{ V}$ | — | — | 1.5 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = -1 \text{ A}, V_{GS} = 0 \text{ V}$ | — | 90 | — | ns |
| Reverse recovery charge | Q_{rr} | $dI_{DR} / dt = 50 \text{ A} / \mu\text{s}$ | — | 180 | — | nC |







$$R_G = 25 \Omega$$

$$V_{DD} = -50 \text{ V}, L = 168 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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